



## BTX18-100/BTX18-200/BTX18-300 BTX18-400/BTX18-500

### SILICON THYRISTORS

The BTX18 series is a range of p-gate reverse blocking thyristors, in a TO-39 metal enveloppe, intended for use in general low power applications up to a A average on-state current.

### RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

#### Anode to Cathode - Ratings

Voltage<sup>1)</sup>

| Symbol    | Ratings  | BTX18-100 | BTX18-200 | BTX18-300 | BTX18-400 | BTX18-500 |                 |
|-----------|--|-----------|-----------|-----------|-----------|-----------|-----------------|
| $V_R$     | Continuous Reverse Voltage                                       | 100       | 200       | 300       | 400       | 500       | V               |
| $V_{RWM}$ | Crest Working Reverse Voltage                                    | 100       | 200       | 300       | 400       | 500       | V               |
| $V_{RRM}$ | Repetitive Peak Reverse Voltage<br>( $\delta = 0.01$ ; f=50Hz)   | 120       | 240       | 350       | 500       | 600       | V               |
| $V_{RSM}$ | Non-repetitive peak reverse voltage<br>(t<10ms)                  | 120       | 240       | 350       | 500       | 600       | V               |
| $V_{DWM}$ | Crest Working off-state Voltage                                  | 100       | 200       | 300       | 400       | 500       | V               |
| $V_D$     | Continuous off-state Voltage                                     | 100       | 200       | 300       | 400       | 500       | V               |
| $V_{DRM}$ | Repetitive peak off-state voltage<br>( $\delta = 0.01$ ; f=50Hz) | 120       | 240       | 350       | 500       | 600       | V <sup>2)</sup> |
| $V_{DSM}$ | Non-repetitive peak off-state voltage<br>(t<10ms)                | 120       | 240       | 350       | 500       | 600       | V <sup>2)</sup> |

#### Currents

| Symbol       | Ratings  | BTX18-100  | BTX18-200 | BTX18-300 | BTX18-400 | BTX18-500 |    |
|--------------|--|--|-----------|-----------|-----------|-----------|----|
| $I_{T(AV)}$  | Average on-state current<br>(averaged over any 20 ms period) | $T_{CASE}=105^\circ C$<br>$T_{AMB}=60^\circ C$ , in free air |           | Max : 1.0 |           |           | A  |
| $I_T$        | On-state Current (D.C.)<br>$T_{CASE}=100^\circ C$            |  |           | Max : 250 |           |           | mA |
| $I_{T(RMS)}$ | RMS on-state Current   |  |           | Max : 1.6 |           |           | A  |

# BTX18-100/BTX18-200/BTX18-300

## BTX18-400/BTX18-500

| Symbol             | Ratings  | BTX18-100 | BTX18-200 | BTX18-300  | BTX18-400 | BTX18-500        |
|--------------------|--|-----------|-----------|--|-----------|------------------|
| $I_{TRM}$          | Repetitive Peak on-state Current   |           |           | Max : 10   |           | A                |
| $I_{TSM}$          | Non-repetitive peak on-state current<br>$t=10\text{ms}$ ; $T_J=125^\circ\text{C}$ prior to surge |           |           | 10 A   |           | V                |
| $T_J$<br>$T_{stg}$ | Junction Temperature<br>Storage Temperature  |           |           | Max : $125^\circ\text{C}$<br>-55 to $+125^\circ\text{C}$ |           | $^\circ\text{C}$ |

- 1) These ratings apply for zero or negative bias on the gate with respect to the cathode, and when a resistor  $R<1\text{ k}\Omega$  is connected between gate and cathode
- 2) The device is not suitable for operation in the forward breakdown mode.

### Gate to Cathode - Ratings

With  $1\Omega$  resistor between gate and cathode

| Symbol      | Ratings  | BTX18-100 | BTX18-200 | BTX18-300  | BTX18-400 | BTX18-500 |
|-------------|--|-----------|-----------|------------|-----------|-----------|
| $V_{FGM}$   | Forward Peak Voltage                                       |           |           | Max : 10 V |           | V         |
| $V_{RGM}$   | Reverse Peak Voltage                                       |           |           | Max : 5 V  |           | V         |
| $I_{FGM}$   | Forward Peak Current                                       |           |           | Max : 0.2  |           | A         |
| $P_{G(AV)}$ | Average Power Dissipation (averaged over any 20 ms period) |           |           | Max : 0.05 |           | W         |
| $P_{GM}$    | Peak Power Dissipation                                     |           |           | Max : 0.5  |           | W         |

### Temperatures

| Symbol       | Ratings   | BTX18-100 | BTX18-200 | BTX18-300 | BTX18-400 | BTX18-500          |
|--------------|---|-----------|-----------|-----------|-----------|--------------------|
| $R_{th j-c}$ | From Junction to Case                             |           |           | 10        |           | $^\circ\text{C/W}$ |
| $R_{th j-a}$ | From Junction to Ambient                          |           |           | 200       |           | $^\circ\text{C/W}$ |
| $Z_{th j-c}$ | Transient Thermal Resistance ( $t=10\text{ ms}$ ) |           |           | 2.5       |           | $^\circ\text{C/W}$ |

### Anode to Cathode - Characteristics

| Symbol | Ratings  | BTX18-100 | BTX18-200 | BTX18-300 | BTX18-400 | BTX18-500 |               |
|--------|--|-----------|-----------|-----------|-----------|-----------|---------------|
| $V_T$  | On State Voltage<br>$I_T=1.0\text{ A}, T_J=25^\circ\text{C}$ | < 1.5     | 1.5       | 1.5       | 1.5       | 1.5       | $\text{V}^1)$ |

# BTX18-100/BTX18-200/BTX18-300

## BTX18-400/BTX18-500

| Symbol   | Ratings  |   | BTX18<br>-100 | BTX18<br>-200 | BTX18<br>-300     | BTX18<br>-400 | BTX18<br>-500 |         |
|----------|--|---|---------------|---------------|-------------------|---------------|---------------|---------|
| $I_{RM}$ | Peak Reverse Current<br>$V_{RM}=V_{RWmax}$ ; $T_j=125^\circ C$   | < | 800           | 400           | 275               | 200           | 160           | $\mu A$ |
| $I_{DM}$ | Peak off-state Current<br>$V_{DM}=V_{DWmax}$ ; $T_j=125^\circ C$ | < | 800           | 400           | 275               | 200           | 160           | $\mu A$ |
| $I_L$    | Latching current, $T_j=125^\circ C$                              |   |               |               | Typ : 10          |               |               | $mA$    |
| $I_H$    | Holding Current ; $T_j=25^\circ C$                               | < |               |               | 5.0 <sup>2)</sup> |               |               | $mA$    |

### Gate to Cathode – Characteristics

| Symbol   | Ratings   |   | BTX18<br>-100 | BTX18<br>-200 | BTX18<br>-300 | BTX18<br>-400 | BTX18<br>-500 |      |
|----------|---|---|---------------|---------------|---------------|---------------|---------------|------|
| $V_{GT}$ | Voltage that will trigger all devices<br>$T_j=25^\circ C$     | > |               |               | 2.0           |               |               | $V$  |
| $V_{GD}$ | Voltage that will not trigger any device<br>$T_j=125^\circ C$ | < |               |               | 200           |               |               | $mV$ |
| $I_{GT}$ | Current that will trigger all devices<br>$T_j=25^\circ C$     | > |               |               | 5.0           |               |               | $mA$ |

### Switching Characteristics

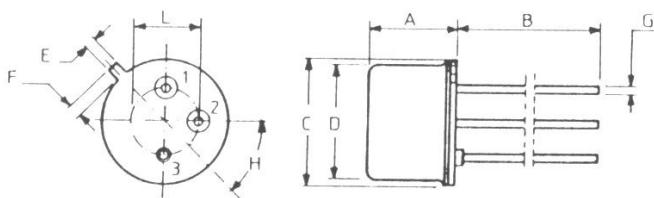
| Symbol   | Ratings  |       | BTX18<br>-100 | BTX18<br>-200 | BTX18<br>-300 | BTX18<br>-400 | BTX18<br>-500 |         |
|--|--|-------|---------------|---------------|---------------|---------------|---------------|---------|
| Turn off time when switched from<br>$IT=300\text{ mA}$ to $IR=175\text{ mA}$ | $T_j=25^\circ C$<br>$T_j=125^\circ C$                            | $t_q$ |               |               | Type : 20     |               |               | $\mu s$ |
|  |  |       |               |               | Typ : 35      |               |               |         |
| $I_{DM}$   | Peak off-state Current<br>$V_{DM}=V_{DWmax}$ ; $T_j=125^\circ C$ | <     | 800           | 400           | 275           | 200           | 160           | $\mu s$ |

- 1)  $V_T$  is measured along the leads at 1 cm from the case
- 2) Measured under the following conditions :
  - Anode supply voltage = +6.0V
  - Initial on-state current after gate triggering = 50mA
  - The current is reduced until the device turns off.

# **BTX18-100/BTX18-200/BTX18-300 BTX18-400/BTX18-500**

## **MECHANICAL DATA CASE TO-39**

| DIMENSIONS |      |        |
|------------|------|--------|
|            | mm   | inches |
| A          | 6,71 | 0,26   |
| B          | 13,2 | 0,51   |
| C          | 9,23 | 0,36   |
| D          | 8,34 | 0,32   |
| E          | 0,8  | 0,03   |
| F          | 0,8  | 0,03   |
| G          | 0,42 | 0,016  |
| H          | 45°  |        |
| L          | 4,97 | 0,2    |



|         |         |
|---------|---------|
| Pin 1 : | Kathode |
| Pin 2 : | Gate    |
| Pin 3 : | Anode   |